

Dear customers,

About the change in the name such as "Oki Electric Industry Co. Ltd." and "OKI" in documents to OKI Semiconductor Co., Ltd.

The semiconductor business of Oki Electric Industry Co., Ltd. was succeeded to OKI Semiconductor Co., Ltd. on October 1, 2008. Therefore, please accept that although the terms and marks of "Oki Electric Industry Co., Ltd.", "Oki Electric", and "OKI" remain in the documents, they all have been changed to "OKI Semiconductor Co., Ltd.". It is a change of the company name, the company trademark, and the logo, etc., and NOT a content change in documents.

October 1, 2008 OKI Semiconductor Co., Ltd.

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OKI Semiconductor

MSM5117805F

2.097.152-Word × 8-Bit DYNAMIC RAM : FAST PAGE MODE TYPE WITH EDO

DESCRIPTION

The MSM5117805F is a 2,097,152-word × 8-bit dynamic RAM fabricated in Oki's silicon-gate CMOS technology. The MSM5117805F achieves high integration, high-speed operation, and low-power consumption because Oki manufactures the device in a quadruple-layer polysilicon/double-layer metal CMOS process. The MSM5117805F is available in a 28-pin plastic SOJ or 28-pin plastic TSOP.

FEATURES

 \cdot 2,097,152-word \times 8-bit configuration

· Single 5V power supply, ±10% tolerance

· Input : TTL compatible, low input capacitance

· Output : TTL compatible, 3-state

· Refresh: 2048 cycles/32ms

· Fast page mode with EDO, read modify write capability

 $\cdot \overline{\text{CAS}}$ before $\overline{\text{RAS}}$ refresh, hidden refresh, $\overline{\text{RAS}}$ -only refresh capability

· Packages

28-pin 400mil plastic SOJ (SOJ28-P-400-1.27) (Product : MSM5117805F-xxJS) 28-pin 400mil plastic TSOP (TSOPII28-P-400-1.27-K) (Product : MSM5117805F-xxTS-K)

xx indicates speed rank.

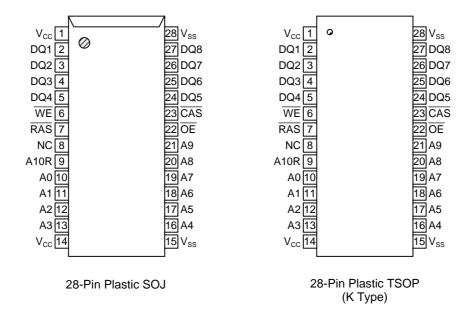
This version: November. 2000

Previous version: ---

PRODUCT FAMILY

| Family | | Access Ti | me (Max.) | | Cycle Time | Power Dissipation | | |
|-------------|------------------|-----------------|------------------|------------------|------------|-------------------|-------------------|--|
| | t _{RAC} | t _{AA} | t _{CAC} | t _{OEA} | (Min.) | Operating (Max.) | Standby (Max.) | |
| MSM5117805F | 50ns | 25ns | 13ns | 13ns | 84ns 550mW | | | |
| | 7805F 60ns 30ns | | 15ns | 15ns | 104ns | 495mW | 5.5mW | |
| | 70ns | 35ns | 20ns | 20ns | 124ns | 440mW | | |

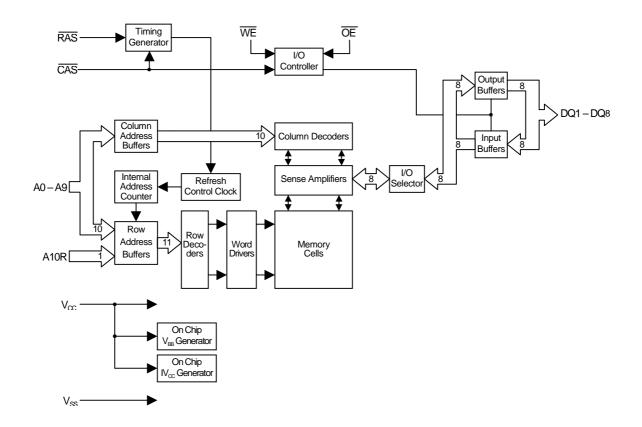
PIN CONFIGURATION (TOP VIEW)



| Pin Name | Function |
|-----------------|------------------------|
| A0-A9, A10R | Address Input |
| RAS | Row Address Strobe |
| CAS | Column Address Strobe |
| DQ1-DQ8 | Data Input/Data Output |
| ŌĒ | Output Enable |
| WE | Write Enable |
| V _{CC} | Power Supply (5V) |
| V _{SS} | Ground (0V) |
| NC | No Connection |

Note: The same power supply voltage must be provided to every V_{CC} pin, and the same GND voltage level must be provided to every V_{SS} pin.

BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|--|------------------------------------|------------------------------|------|
| Voltage on Any Pin Relative V _{SS} | V _{IN} , V _{OUT} | -0.5 to V _{CC} +0.5 | V |
| Voltage V _{CC} Supply relative to V _{SS} | V _{CC} | -0.5 to 7.0 | V |
| Short Circuit Output Current | I _{OS} | 50 | MA |
| Power Dissipation | P _{D*} | 1 | W |
| Operating Temperature | T _{opr} | 0 to 70 | °C |
| Storage Temperature | T _{stg} | -55 to 150 | °C |

^{*:} Ta = 25°C

RECOMMENDED OPERATING CONDITION

 $(Ta = 0 \text{ to } 70^{\circ}C)$

| Parameter | Symbol | Min. | Тур. | Max. | Unit |
|----------------------|-----------------|---------------------|------|-------------|------|
| Power Supply Voltage | V _{CC} | 4.5 | 5.0 | 5.5 | V |
| | V_{SS} | 0 | 0 | 0 | V |
| Input High Voltage | V _{IH} | 2.4 | _ | Vcc + 0.5*1 | V |
| Input Low Voltage | V _{IL} | - 0.5 ^{*2} | _ | 0.8 | V |

Notes: *1. The input voltage is $V_{CC} + 2.0V$ when the pulse width is less than 20ns (the pulse width is with respect to the point at which V_{CC} is applied).

PIN CAPACITANCE

 $(Vcc=5V\pm10\%,\,Ta=25^{\circ}C,\ f=1\ MHz)$

| Parameter | Symbol | Min. | Max. | Unit |
|---|------------------|------|------|------|
| Input Capacitance (A0 – A9, A10R) | C _{IN1} | _ | 5 | pF |
| Input Capacitance (RAS, CAS, WE, OE) | C _{IN2} | 1 | 7 | pF |
| Output Capacitance (DQ1 – DQ8) | C _{I/O} | _ | 7 | pF |

^{*2.} The input voltage is $V_{SS} - 2.0V$ when the pulse width is less than 20ns (the pulse width respect to the point at which V_{SS} is applied).

DC CHARACTERISTICS

 $(V_{CC} = 5V \pm 10\%, Ta = 0 \text{ to } 70^{\circ}C)$

| | | | | | | 1,,,, | | 1070, 14 | _ 0 .0 | |
|---|------------------|---|------|-----------------|--------------------|-----------------|--------------------|-----------------|--------|------|
| Parameter | Symbol Condition | | | 117805 50 | MSM5117805 F-60 | | MSM5117805 F-70 | | Unit | Note |
| | | | Min. | Max. | Min. | Max. | Min. | Max. | | |
| Output High Voltage | V _{OH} | I _{OH} = -5.0mA | 2.4 | V _{CC} | 2.4 | V _{CC} | 2.4 | V _{CC} | V | |
| Output Low Voltage | V _{OL} | I _{OL} = 4.2mA | 0 | 0.4 | 0 | 0.4 | 0 | 0.4 | ٧ | |
| Input Leakage Current | lLI | $0V \le V_{\parallel} \le 6.5V;$ All other pins not under test = $0V$ | - 10 | 10 | - 10 | 10 | - 10 | 10 | μА | |
| Output Leakage Current | I _{LO} | DQ disable $0V \le V_O \le V_{CC}$ | - 10 | 10 | - 10 | 10 | - 10 | 10 | μΑ | |
| Average Power Supply Current (Operating) | I _{CC1} | \overline{RAS} , \overline{CAS} cycling, $t_{RC} = Min$. | _ | 100 | _ | 90 | _ | 80 | mA | 1,2 |
| Power Supply | | RAS, CAS = V _{IH} | _ | 2 | _ | 2 | _ | 2 | | |
| Current (Standby) | I _{CC2} | $\overline{\text{RAS}}, \overline{\text{CAS}}$ $\geq V_{\text{CC}} - 0.2V$ | _ | 1 | _ | 1 | _ | 1 | mA | 1 |
| Average Power Supply Current (RAS-only Refresh) | I _{CC3} | $\overline{RAS} \text{ cycling,}$ $\overline{CAS} = V_{IH},$ $t_{RC} = \text{Min.}$ | _ | 100 | _ | 90 | _ | 80 | mA | 1,2 |
| Power Supply Current (Standby) | I _{CC5} | $\overline{RAS} = V_{IH},$ $\overline{CAS} = V_{IL},$ $DQ = enable$ | _ | 5 | _ | 5 | _ | 5 | mA | 1 |
| Average Power Supply Current (CAS before RAS Refresh) | I _{CC6} | RAS = cycling, CAS before RAS | _ | 100 | _ | 90 | _ | 80 | mA | 1,2 |
| Average Power Supply Current (Fast Page Mode) | I _{CC7} | $\overline{RAS} = V_{IL},$ $\overline{CAS} \ cycling,$ $t_{HPC} = Min.$ | _ | 100 | _ | 90 | _ | 80 | mA | 1,3 |

Notes: 1. I_{CC} Max. is specified as I_{CC} for output open condition.

- 2. The address can be changed once or less while \overline{RAS} = V_{IL} .
- 3. The address can be changed once or less while \overline{CAS} = V_{IH} .

AC CHARACTERISTICS (1/3)

(V_{CC} = 5V \pm 10%, Ta = 0 to 70°C) Note1,2,3

| | MSM5117805 | | | | | 10%, $1a = 0$ to 70 MSM5117805 | | C) NO | Jie 1,2,3 |
|---|--------------------|------|---------------|------|--------------|--------------------------------|--------------|-------|-----------|
| Parameter | Symbol | | 117805 ·50 | | 117805 60 | | 117805 70 | Unit | Note |
| | | Min. | Max. | Min. | Max. | Min. | Max. | | |
| Random Read or Write Cycle Time | t _{RC} | 84 | _ | 104 | _ | 124 | _ | ns | |
| Read Modify Write Cycle Time | t _{RWC} | 110 | _ | 135 | _ | 160 | _ | ns | |
| Fast Page Mode Cycle Time | tHPC | 20 | _ | 25 | | 30 | _ | ns | |
| Fast Page Mode Read Modify Write Cycle Time | t _{HPRWC} | 58 | | 68 | | 78 | _ | ns | |
| Access Time from RAS | t _{RAC} | | 50 | | 60 | | 70 | ns | 4, 5, 6 |
| Access Time from CAS | tCAC | | 13 | | 15 | | 20 | ns | 4,5 |
| Access Time from Column Address | t _{AA} | | 25 | | 30 | | 35 | ns | 4,6 |
| Access Time from CAS Precharge | tCPA | _ | 30 | _ | 35 | _ | 40 | ns | 4 |
| Access Time from OE | tOEA | | 13 | _ | 15 | | 20 | ns | 4 |
| Output Low Impedance Time from CAS | t _{CLZ} | 0 | _ | 0 | _ | 0 | _ | ns | 4 |
| Data Output Hold After CAS Low | tDOH | 5 | | 5 | _ | 5 | _ | ns | |
| CAS to Data Output Buffer Turn- off Delay Time | tCEZ | 0 | 13 | 0 | 15 | 0 | 20 | ns | 7,8 |
| RAS to Data Output Buffer Turn- off Delay Time | t _{REZ} | 0 | 13 | 0 | 15 | 0 | 20 | ns | 7,8 |
| OE to Data Output Buffer Turn-off Delay Time | t _{OEZ} | 0 | 13 | 0 | 15 | 0 | 20 | ns | 7 |
| WE to Data Output Buffer Turn- off Delay Time | t _{WEZ} | 0 | 13 | 0 | 15 | 0 | 20 | ns | 7 |
| Transition Time | t _T | 1 | 50 | 1 | 50 | 1 | 50 | ns | 3 |
| Refresh Period | t _{REF} | _ | 32 | _ | 32 | _ | 32 | ms | |
| RAS Precharge Time | t _{RP} | 30 | _ | 40 | _ | 50 | _ | ns | |
| RAS Pulse Width | t _{RAS} | 50 | 10,000 | 60 | 10,000 | 70 | 10,000 | ns | |
| RAS Pulse Width (Fast Page Mode with EDO) | t _{RASP} | 50 | 100,000 | 60 | 100,000 | 70 | 100,000 | ns | |
| RAS Hold Time | tRSH | 7 | _ | 10 | _ | 13 | _ | ns | |
| RAS Hold Time referenced to OE | tROH | 7 | | 10 | | 13 | _ | ns | |
| CAS Precharge Time (Fast Page Mode with EDO) | t _{CP} | 7 | _ | 10 | _ | 10 | _ | ns | |
| CAS Pulse Width | tCAS | 7 | 10,000 | 10 | 10,000 | 13 | 10,000 | ns | |
| CAS Hold Time | tCSH | 35 | | 40 | | 45 | | ns | |

AC CHARACTERISTICS (2/3)

(V_{CC} = 5V \pm 10%, Ta = 0 to 70°C) Note1,2,3

| Parameter | Symbol | | 117805 50 | MSM5117805 F-60 | | MSM5117805 F-70 | | Unit | Note |
|--|-------------------|------|--------------|--------------------|------|--------------------|------|-------|------|
| Farameter | Symbol | Min. | Max. | Min. | Max. | Min. | Max. | Offic | Note |
| CAS to RAS Precharge Time | tCRP | 5 | _ | 5 | _ | 5 | _ | ns | |
| RAS Hold Time from CAS Precharge | t _{RHCP} | 30 | _ | 35 | _ | 40 | _ | ns | |
| OE Hold Time from CAS (DQ Disable) | t _{CHO} | 5 | _ | 5 | _ | 5 | _ | ns | |
| RAS to CAS Delay Time | t _{RCD} | 11 | 37 | 14 | 45 | 14 | 50 | ns | 5 |
| RAS to Column Address Delay Time | t _{RAD} | 9 | 25 | 12 | 30 | 12 | 35 | ns | 6 |
| Row Address Set-up Time | t _{ASR} | 0 | _ | 0 | _ | 0 | _ | ns | |
| Row Address Hold Time | t _{RAH} | 7 | _ | 10 | | 10 | _ | ns | |
| Column Address Set-up Time | tASC | 0 | _ | 0 | | 0 | _ | ns | |
| Column Address Hold Time | tCAH | 7 | _ | 10 | | 13 | _ | ns | |
| Column Address to RAS Lead Time | t _{RAL} | 25 | _ | 30 | | 35 | _ | ns | |
| Read Command Set-up Time | t _{RCS} | 0 | _ | 0 | | 0 | _ | ns | |
| Read Command Hold Time | t _{RCH} | 0 | _ | 0 | | 0 | _ | ns | 9 |
| Read Command Hold Time referenced to RAS | t _{RRH} | 0 | _ | 0 | _ | 0 | _ | ns | 9 |
| Write Command Set-up Time | twcs | 0 | _ | 0 | _ | 0 | _ | ns | 10 |
| Write Command Hold Time | tWCH | 7 | _ | 10 | _ | 13 | _ | ns | |
| Write Command Pulse Width | t _{WP} | 7 | _ | 10 | _ | 10 | _ | ns | |
| WE Pulse Width (DQ Disable) | t _{WPE} | 7 | _ | 10 | _ | 10 | _ | ns | |
| OE Command Hold Time | tOEH | 7 | _ | 10 | _ | 13 | _ | ns | |
| OE Precharge Time | tOEP | 7 | _ | 10 | _ | 10 | _ | ns | |
| OE Command Hold Time | toch | 7 | _ | 10 | _ | 10 | _ | ns | |
| Write Command to RAS Lead Time | t _{RWL} | 7 | _ | 10 | _ | 13 | _ | ns | |
| Write Command to CAS Lead Time | t _{CWL} | 7 | _ | 10 | _ | 13 | _ | ns | |
| Data-in Set-up Time | t _{DS} | 0 | _ | 0 | _ | 0 | _ | ns | 11 |
| Data-in Hold Time | t _{DH} | 7 | _ | 10 | _ | 13 | _ | ns | 11 |
| OE to Data-in Delay Time | tOED | 13 | _ | 15 | _ | 20 | _ | ns | |
| CAS to WE Delay Time | tCWD | 30 | | 34 | | 44 | | ns | 10 |
| Column Address to WE Delay Time | t _{AWD} | 42 | _ | 49 | _ | 59 | | ns | 10 |
| RAS to WE Delay Time | t _{RWD} | 67 | | 79 | _ | 94 | | ns | 10 |
| CAS Precharge WE Delay Time | tCPWD | 47 | | 54 | | 64 | | ns | 10 |

AC CHARACTERISTICS (3/3)

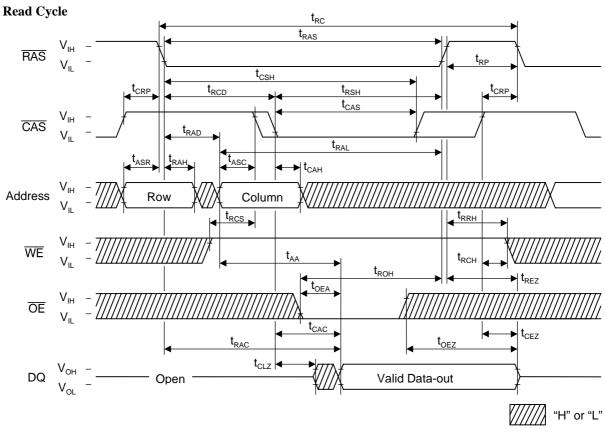
(V_{CC} = 3.3V \pm 0.3V, Ta = 0 to 70°C) Note1,2,3

| | | | | , 00 | | | | | |
|--|------------------|--------------------|------|--------------------|------|--------------------|------|--------------------------|------|
| Parameter | Symbol | MSM5117805 F-50 | | MSM5117805 F-60 | | MSM5117805 F-70 | | Unit | Note |
| | | Min. | Max. | Min. | Max. | Min. | Max. | Unit ns ns ns ns ns | Ì |
| CAS Active Delay Time from RAS Precharge | t _{RPC} | 5 | _ | 5 | _ | 5 | _ | ns | |
| RAS to CAS Set-up Time (CAS before RAS) | t _{CSR} | 5 | _ | 5 | _ | 5 | _ | ns | |
| RAS to CAS Hold Time (CAS before RAS) | tCHR | 10 | _ | 10 | _ | 10 | _ | ns | |
| WE to CAS Hold Time (CAS before RAS) | t _{WRP} | 10 | _ | 10 | _ | 10 | _ | ns | |
| WE Hold Time from RAS (CAS before RAS) | t _{WRH} | 10 | _ | 10 | _ | 10 | _ | ns | |
| RAS to WE Set-up Time | t _{WTS} | 10 | _ | 10 | _ | 10 | _ | ns | |
| RAS to WE Hold Time | t _{WTH} | 10 | _ | 10 | _ | 10 | _ | ns | |

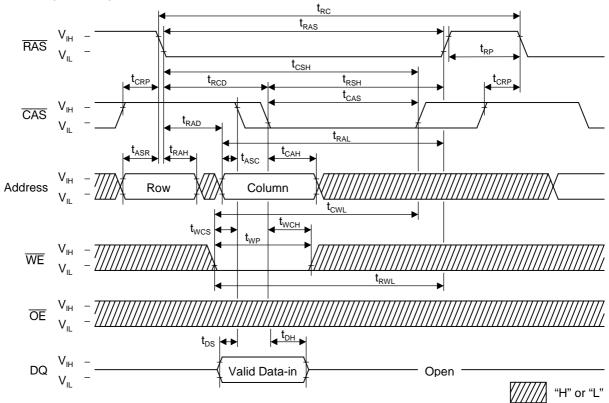
Notes: 1. A start-up delay of 200µs is required after power-up, followed by a minimum of eight initialization cycles (RAS-only refresh or CAS before RAS refresh) before proper device operation is achieved.

- 2. The AC characteristics assume $t_T = 2ns$.
- 3. V_{IH} (Min.) and V_{IL} (Max.) are reference levels for measuring input timing signals. Transition times (t_T) are measured between V_{IH} and V_{IL} .
- 4. -50 is measured with a load circuit equivalent to 2TTL load and 50pF, and -60/-70 is measured with a load circuit equivalent to 2TTL load and 100pF.
- Operation within the t_{RCD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RCD} (Max.) is specified as a reference point only. If t_{RCD} is greater than the specified t_{RCD} (Max.) limit, then the access time is controlled by t_{CAC}.
- 6. Operation within the t_{RAD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RAD} (Max.) is specified as a reference point only. If t_{RAD} is greater than the specified t_{RAD} (Max.) limit, then the access time is controlled by t_{AA} .
- 7. t_{CEZ} (Max.), t_{REZ} (Max.), t_{WEZ} (Max.), and t_{OEZ} (Max.) define the time at which the output achieved the open circuit condition and are not referenced to output voltage levels.
- 8. t_{CEZ} , and t_{REZ} must be satisfied for open circuit condition.
- 9. t_{RCH} or t_{RRH} must be satisfied for a read cycle.
- 10. t_{WCS} , t_{CWD} , t_{RWD} , t_{AWD} and t_{CPWD} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If $t_{WCS} \ge t_{WCS}$ (Min.), then the cycle is an early write cycle and the data out will remain open circuit (high impedance) throughout the entire cycle. If $t_{CWD} \ge t_{CWD}$ (Min.), $t_{RWD} \ge t_{RWD}$ (Min.), $t_{RWD} \ge t_{RWD}$ (Min.) and $t_{CPWD} \ge t_{CPWD}$ (Min.), then the cycle is a read modify write cycle and data out will contain data read from the selected cell; if neither of the above sets of conditions is satisfied, then the condition of the data out (at access time) is indeterminate.
- 11. These parameters are referenced to the \overline{CAS} , leading edges in an early write cycle, and to the \overline{WE} leading edge in an \overline{OE} control write cycle, or a read modify write cycle.

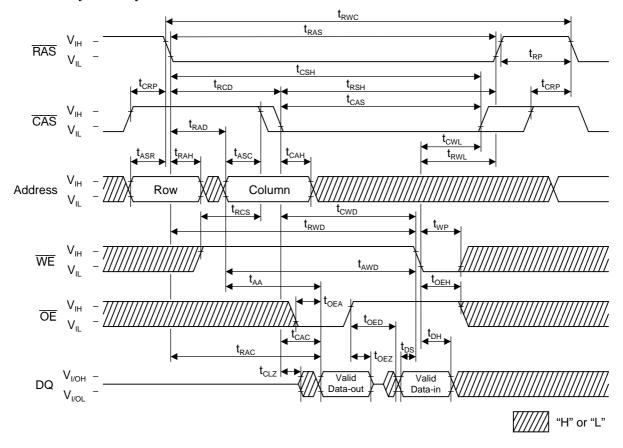
TIMING CHART



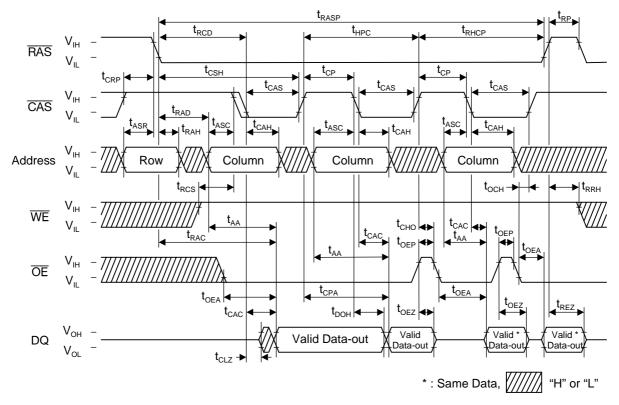
Write Cycle (Early Write)



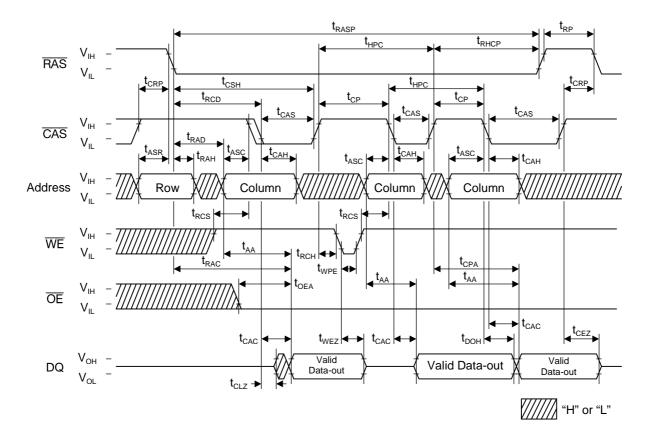
Read Modify Write Cycle



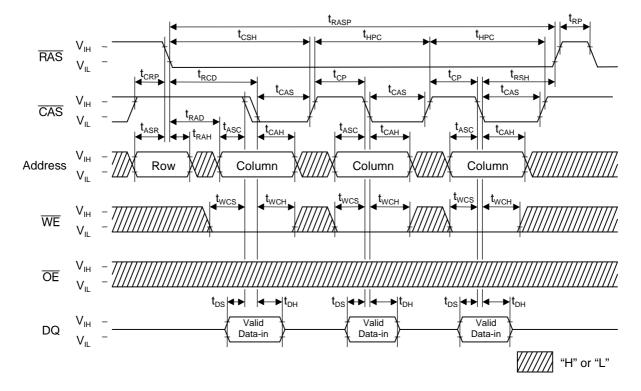
Fast Page Mode Read Cycle (Part-1)



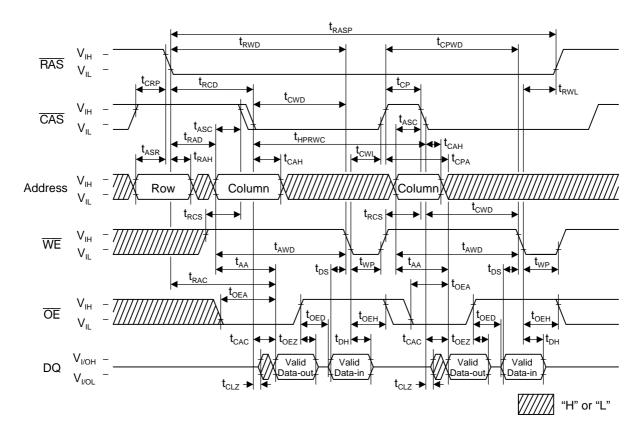
Fast Page Mode Read Cycle (Part-2)



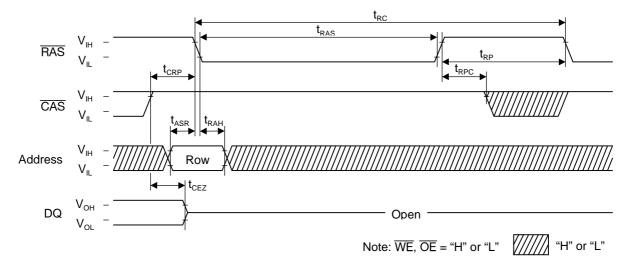
Fast Page Mode Write Cycle (Early Write)



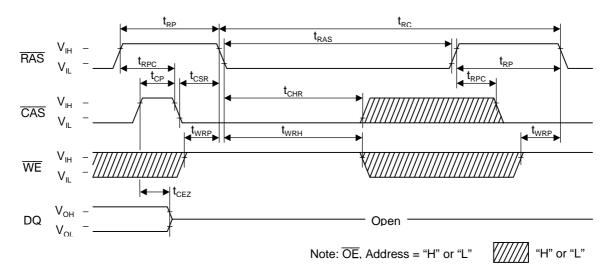
Fast Page Mode Read Modify Write Cycle



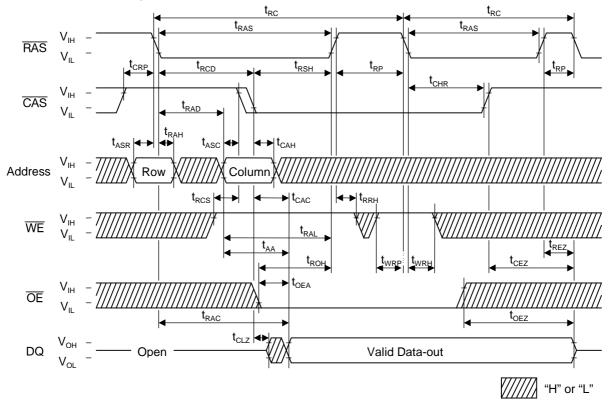
RAS-only Refresh Cycle



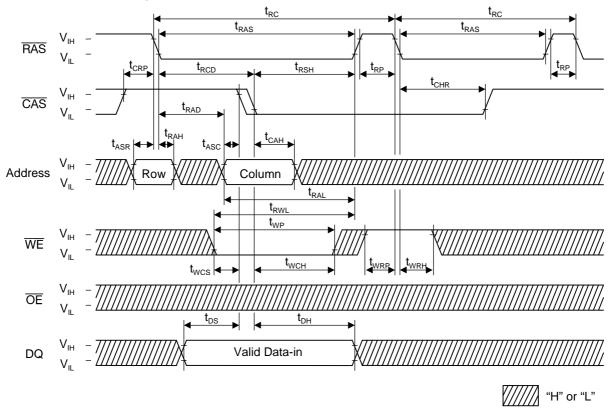
$\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ Refresh Cycle



Hidden Refresh Read Cycle



Hidden Refresh Write Cycle



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